

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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Silicon Photodiode

FEATURES

- Miniature, hermetically sealed, pill style, metal can package
- 48° (nominal) acceptance angle
- Wide operating temperature range (- 55° C to $+125^{\circ}$ C)
- Ideal for direct mounting to printed circuit boards
- Mechanically and spectrally matched to SE2460 and SE2470 infrared emitting diodes



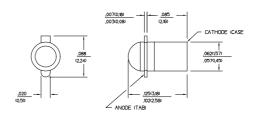
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DESCRIPTION

The SD2420 is a PN silicon photodiode mounted in a hermetically sealed, glass lensed, metal can package. This package directly mounts in double sided PC boards.

OUTLINE DIMENSIONS in inches (mm)

3 plc decimals ±0.005(0.12) 2 plc decimals ±0.020(0.51)



DIM_014.cdr



Silicon Photodiode

ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	TEST CONDITIONS
Light Current SD2420-002	l _L	7.0			μΑ	V _R =20 V H=20 mW/cm ^{2 (1)}
Dark Current	ID			5.0	nA	V _R =20 V H=0
Reverse Breakdown Voltage	V_{BR}	50			V	I _R =10 μA
Angular Response (2)	Ø		48		degr.	I _F =Constant
Rise And Fall Time	t _r , t _f		50		ns	V _R =20 V R _L =50 Ω

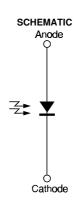
- Notes
 1. The radiation source is a tungsten lamp operating at a color temperature of 2870°K.
 2. Angular response is defined as the total included angle between the half sensitivity points.

ABSOLUTE MAXIMUM RATINGS

(25°C Free-Air Temperature unless otherwise noted) Cathode Anode Voltage 125 mW (1) Power Dissipation Operating Temperature Range -55°C to 125°C -65°C to 150°C Storage Temperature Range Soldering Temperature (10 sec)

Notes

Derate linearly from 25°C free-air temperature at the rate of 1.19 mW/°C.



Silicon Photodiode

SWITCHING TIME TEST CIRCUIT

Q + GaAs Emitter Anode 10 μS

SWITCHING WAVEFORM

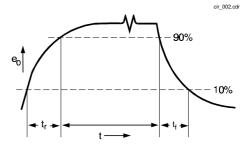


Fig. 1 Responsivity vs Angular Displacement gra_037.ds4 1.0 0.9 0.8 Relative response 0.7 0.6 0.5 0.4 0.3

-15 Ó

Angular displacement - degrees

+15 +30 +45

Fig. 2 Dark Current vs

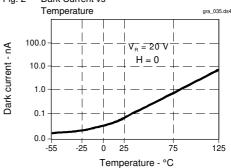
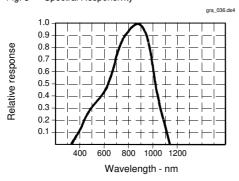


Fig. 3 Spectral Responsivity

-45 -30

0.2

0.0



All Performance Curves Show Typical Values



Silicon Photodiode